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Schottky Diode	V _{RRM}	=	25 V
	I _{FAV}	=	6 A
	V _F	=	0.3 V

High Performance Schottky Diode Low Loss and Soft Recovery Single Diode

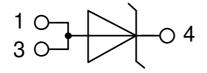
Part number

DSS6-0025BS

Marking on Product: 6Y025AS



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
 Low voltage peaks for reduced
- protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-252 (DPak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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IXYS reserves the right to change limits, conditions and dimensions.



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Schottky					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			25	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			25	V
I _R	reverse current, drain current	$V_{R} = 25 V$	$T_{VJ} = 25^{\circ}C$			5	mA
		$V_{R} = 25 V$	$T_{vJ} = 100^{\circ}C$			40	mA
V _F	forward voltage drop	I _F = 6 A	$T_{VJ} = 25^{\circ}C$			0.40	V
		I _F = 12 A				0.47	V
		I _F = 6 A	T _{vJ} = 125°C			0.30	V
		I _F = 12 A				0.40	V
FAV	average forward current	T _c = 140°C	T _{vJ} = 150°C			6	Α
		rectangular d = 0.5					
V _{F0}	threshold voltage		T _{vJ} = 150°C			0.18	V
r _F	slope resistance } for power lo	ess calculation only				15.9	mΩ
R _{thJC}	thermal resistance junction to case	e				3	K/W
R _{thCH}	thermal resistance case to heatsin	ık			0.50		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			40	W
FSM	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			120	A
C	junction capacitance	$V_{R} = 5V f = 1 MHz$	$T_{vJ} = 25^{\circ}C$		639		pF

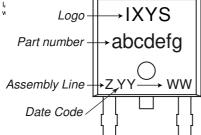
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Package	Package TO-252 (DPak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I _{RMS}	RMS current	per terminal "			20	Α	
T _{vj}	virtual junction temperature		-55		150	°C	
T _{op}	operation temperature		-55		125	°C	
T _{stg}	storage temperature		-55		150	°C	
Weight	Product Marking			0.3		g	
F _c	mounting force with clip		20		60	Ν	
¹⁾ I _r		of the chip (2). In case of (1) and a prost		1	1		



of the chip (2). In case of (1) and a pro connecting the pins as one contact.

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSS6-0025BS-TRL	6Y025AS	Tape & Reel	2500	499064
Alternative	DSS6-0025BS-TUB	6Y025AS	Tube	70	525007

Equiva	alent Circuits for	Simulation	* on die level	$T_{VJ} = 150 \ ^{\circ}C$
) Ro -	Schottky		
V _{0 max}	threshold voltage	0.18		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	12.8		mΩ

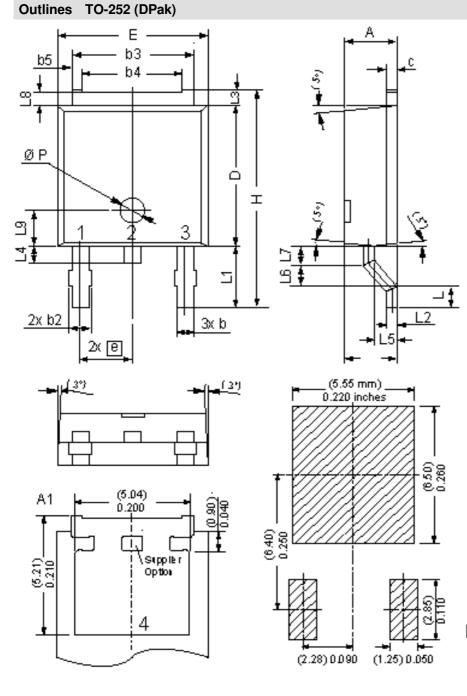
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Dim	Millimeters		Inches	
min min		max	min	max
A	2.20	2.40	0.087	0.094
A1	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b2	-	0.96	-	0.038
b3	5.04	5.64	0.198	0.222
b4	4.34	BSC	0.171	BSC
b5	0.50	BSC	0.020	BSC
С	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
Е	6.40	6.80	0.252	0.268
е	2.10	2.50	0.083	0.098
Н	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L1	2.50	2.90	0.098	0.114
L2	0.40	0.60	0.016	0.024
L3	0.50	0.90	0.020	0.035
L4	0.60	1.00	0.024	0.039
L5	0.82	1.22	0.032	0.048
L6	0.79	0.99	0.031	0.039
L7	0.81	1.01	0.032	0.040
L8	0.40	0.80	0.016	0.031
L9	1.50	BSC	0.059	BSC
ØΡ	1.00	BSC	0.039	BSC

Recommended min. foot print

